ELECTRONICS, INC.
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1N821A thru 1N829A
Zener Diode, Temperature Compensating, 5.9V to 6.5V

Features:

- DO–7 Package

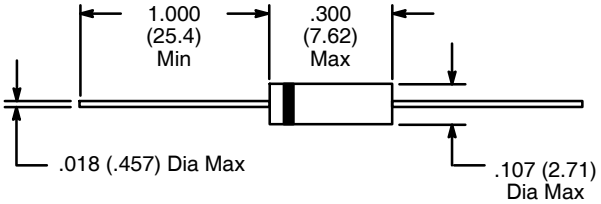
Absolute Maximum Ratings: (T_A = +25°C unless otherwise specified)

Operating Junction Temperature Range, T_{opr} . . . . . –55° to +100°C
Storage Temperature Range, T_{stg} . . . . . –55° to +100°C
Forward Voltage (I_F = 200mA), V_F 1.1V
DC Power Dissipation (T_A = +50), P_D 500mW
Deratve Above +50°C . . . . . 3.33mW/°C

Electrical Characteristics: (T_C = +25°C, unless otherwise specified)

NTE Type Number	Zener Voltage V_z @ I_{zt} (Note 3)	Zener Test Current (I_{zt})	Max. Zener Impedance (Z_{zt}) (Note 2 & 3)	Voltage Temperature Stability (Note 1 ,2 & 3)	Typical Temperature Coefficient α_{vz}
			Z_{zt} @ I_{zt}	ΔV_{zt}	
	Volts	mA	Ohms	mV	%/°C
1N821A	5.9–6.5	7.5	10	96	0.01
1N823A	5.9–6.5	7.5	10	48	0.005
1N825A	5.9–6.5	7.5	10	19	0.002
1N827A	5.9–6.5	7.5	10	9	0.001
1N829A	5.9–6.5	7.5	10	5	0.0005

Note 1. Zener impedance is derived by superimposing on lzt a 60Hz A.C current equal to 10% of IZT
Note 2. The maximum allowable change observed over the entire temperature range i.e, the diode voltage will not exceed the specified mV at any discrete temperature between the established limits.
Note 3. Voltage measurments to be performed 15 seconds after application of DC current.



Color Band Denotes Cathode